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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/519,451	09/29/2005	Tatsuo Nishita	033082R235	9723
441	7590 03/20/2006		EXAMINER	
SMITH, GAMBRELL & RUSSELL, LLP			AHMADI, MOHSEN	
	EET, N.W., SUITE 800 ON, DC 20036		ART UNIT	PAPER NUMBER
,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	21., 20 2000		2812	

DATE MAILED: 03/20/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

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		Application No.	Applicant(s)				
Office Action Summary		10/519,451	NISHITA ET AL.				
		Examiner	Art Unit	-			
		Mohsen Ahmadi	2812				
Period fo	The MAILING DATE of this communication app or Reply	ears on the cover sheet with the c	orrespondence address				
WHIC - Exte after - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR REPLY CHEVER IS LONGER, FROM THE MAILING DATE of time may be available under the provisions of 37 CFR 1.13 SIX (6) MONTHS from the mailing date of this communication. O period for reply is specified above, the maximum statutory period were to reply within the set or extended period for reply will, by statute, reply received by the Office later than three months after the mailing ed patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be timustilly apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE	N. sely filed the mailing date of this communication (35 U.S.C. § 133).	:			
Status							
1)[Responsive to communication(s) filed on	_ ·					
2a)□	This action is FINAL . 2b)⊠ This action is non-final.						
3)	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is						
	closed in accordance with the practice under E	x parte Quayle, 1935 C.D. 11, 45	53 O.G. 213.				
Disposit	ion of Claims						
4)🖂	Claim(s) <u>1-8</u> is/are pending in the application.	•					
,	4a) Of the above claim(s) is/are withdraw	vn from consideration.					
5)	Claim(s) is/are allowed.						
6)⊠	Claim(s) <u>1-8</u> is/are rejected.						
	Claim(s) is/are objected to.						
8)	Claim(s) are subject to restriction and/or	r election requirement.					
Applicat	ion Papers						
9)[The specification is objected to by the Examine	r.					
10)🛛	The drawing(s) filed on 29 December 2004 is/a	re: a)⊠ accepted or b)⊡ object	ed to by the Examiner.				
	Applicant may not request that any objection to the	drawing(s) be held in abeyance. See	e 37 CFR 1.85(a).				
	Replacement drawing sheet(s) including the correct			(d).			
11)	The oath or declaration is objected to by the Ex	aminer. Note the attached Office	Action or form PTO-152.				
Priority (under 35 U.S.C. § 119						
• —	Acknowledgment is made of a claim for foreign ☐ All b)☐ Some * c)☐ None of:	priority under 35 U.S.C. § 119(a))-(d) or (f).				
,	1. Certified copies of the priority documents	s have been received.					
	2. Certified copies of the priority documents	s have been received in Applicati	on No				
	3. Copies of the certified copies of the prior	rity documents have been receive	ed in this National Stage				
	application from the International Bureau	·					
* 5	See the attached detailed Office action for a list	of the certified copies not receive	ed.				
Attachmer	nt(s)						
	ce of References Cited (PTO-892)	4) Interview Summary					
	ce of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08)	Paper No(s)/Mail Da 5) Notice of Informal F	ate Patent Application (PTO-152)				
	er No(s)/Mail Date <u>12/29/2004</u> .	6) Other:					

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DETAILED ACTION

The application number 10/519451 for a "Method of Oxidizing Member to be Treated" field July 05, 2002 has been examined.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 1, 2, 3, 5 and 6 are rejected under 35 U.S.C. 102(e) as being anticipated by Shoichi et al. (EP Pat. 1 152 461).

Regarding claim 1, Shoichi et al. discloses a method for oxidation of a surface of an object to be process, method characterized by performing oxidation wherein an active hydroxyl species and active oxygen species are mainly used in a vacuum atmosphere, a processing pressure is determined to be 133 Pa or below, and a processing temperature is determined to be 400 degree C or above (See page. 3 paragraphs [0013-0022-24]).

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Regarding claim 2, Shoichi et al. discloses a method for oxidation of an object to be processed, characterized by feeding an oxidizing gas and a reducing gas into processing container respectively by separate gas supply systems in order to produce active oxygen species and active hydroxyl species (See page. 3 paragraphs [0014-0015]).

Regarding claim 3, Shoichi et al. discloses a method for oxidation of an object to be processed, characterized in that: oxidizing gas includes one or more gasses selected from a group of O₂, N₂O, NO, reducing gas is H₂, and H₂ concentration inside processing container is 40% or below (See pages. 3 and 7 paragraphs [0020 and 0064]).

Regarding claim 5, Shoichi et al. discloses a method for oxidation of an object to be processed, characterized in that H2 concentration is within the range from 5 to 33% (See page. 7 paragraph [0070]).

Regarding claim 6, Shoichi et al. discloses a method for oxidation of an object to be processed, characterized in that processing temperature is within the range from 800 to 1,000 degree C (See page. 3 paragraph [0024]).

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

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(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 4, 7 and 8 are rejected under 35 U.S.C. 103(a) as being unpatentable over Shoichi et al. (EP Pat. 1 152 461) in view of Miner et al. (US Pat. 6,114,258).

Regarding claim 4, Shoichi et al. is relied upon as discussed above.

Shoichi et al. discloses all of the claimed features as stated above except for a nitride film and silicon, which are both exposed on surface of object to be processed.

Miner et al. discloses a method of oxidizing a substrate in the presence of nitride and oxynitride films.

Figure. 2 of Miner et al. discloses a method for oxidation of an object to be processed, characterizing a nitride film and silicon, which are both exposed on surface of object to be processed (See col. 4 lines 27-49).

It would have been obvious to one of ordinary skill in the art, at the time of invention, to use the oxidation process of Shoichi et al. in the process of Miner et al. for its known benefit of oxidizing nitride film and silicon.

Regarding claim 7, Shoichi et al. discloses all of the claimed features as stated above except for a method of oxidation an object to be processed, characterized in that, prior to an oxidation processing, nitride film is formed to

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have an extra thickness corresponding to a thickness of the surface of nitride film to be oxidized.

Miner et al. discloses a method of oxidation an object to be processed, characterized in that, prior to an oxidation processing, nitride film is formed (See col. 4 lines 27-30).

However, Miner et al. did not disclose an extra thickness corresponding to a thickness of the surface of nitride film to be oxidized.

It would have been obvious to one of ordinary skill in the art, to optimize the thickness. The determination of the thickness is a matter of optimization. See In re Aller, 220 F.2d 454, 456, 105 USPQ 233, 235 (CCPA 1955)

Regarding claim 8, Shoichi et al. discloses all of the claimed features as stated above except for a method of oxidation an object to be processed, characterized in that, nitride film is a silicon nitride film (SiN).

Miner et al. discloses a method of oxidation an object to be processed, characterizing where the nitride film is a silicon nitride film (SiN) (See col. 4, lines 34-36).

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Mohsen Ahmadi whose telephone number is 1-571-272-5062. The examiner can normally be reached on Mon-Fri 8:00am-5:00pm.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Michael Lebentritt can be reached on 1-571-272-1873. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pairdirect.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (tollfree).

03/08/2006